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Topological crystalline insulators and Dirac octets in antiperovskites

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We predict a class of topological crystalline insulators in the antiperovskite material family with the chemical formula $A_3BX$. Here the nontrivial topology arises from band inversion between two $J = 3/2$ quartets, which is described by a generalized Dirac equation for a “Dirac octet.” Our work suggests that antiperovskites are promising venues for exploring the cooperative interplay between band topology, crystal symmetry, and electron correlation.

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Topological crystalline insulators (TCIs) [1] are new topological phases of matter in two and three dimensions which exhibit metallic boundary states protected by crystal symmetry, unlike $Z_2$ topological insulators (TIs) that rely on time-reversal symmetry [2–4]. The first realization of topological crystalline insulators has recently been predicted [5] and observed in IV–VI semiconductors SnTe, Pb$_{1-x}$Sn$_x$Se, and Pb$_{1-x}$Sn$_x$Te [6–8]. These TCIs exhibit a variety of novel topological electronic properties such as Dirac mass generation via ferroelectric distortion [9,10] and strain-induced flat band superconductivity [11], which are not only of fundamental interest but also may enable novel device applications [12–16]. On the theoretical frontier, the discovery of TCIs has sparked intensive efforts in classifying topological phases in different crystal symmetry classes [17–24]. Given these developments, there is great interest in finding new TCI materials, especially those outside the family of narrow-gap semiconductors. Recent proposals range from pyrochlore iridates [25] and multilayer graphene [26] to heavy-fermion compounds [27,28].

In this work, based on a combination of topological band theory, $kp$ model, and first-principles calculations, we predict a class of TCIs in the antiperovskite material family $A_3BX$, with Sr$_3$PbO and Ca$_3$PbO as two representatives. Here $A$ denotes alkaline-earth or rare-earth metals (Ca, Sr, La), $B$ denotes main group elements of the $p$ block (Pb, Sn), and $X$ denotes nonmetals (C, N, O) [29]. The antiperovskite structure is based on a perovskite but switches the positions of metal and nonmetal elements [see Fig. 1(a)]. Antiperovskites exhibit a wide range of interesting physical properties, such as superconductivity [30], giant magnetoresistance [31], negative thermal expansion [32], and magnetocaloric [33] effect, due to the cooperative interactions among lattice, spin, and charge degrees of freedom. Our prediction of TCIs in antiperovskites thus opens up a promising venue for topological phases in correlated electron systems.

Our work builds on recent theoretical calculations [34,35] that noted an unusual low-energy band structure in Ca$_3$BiN and Ca$_3$PbO, in which both the conduction and valence bands at the $\Gamma$ point are $J = \frac{3}{2}$ multiplets with fourfold degeneracy, which correspond to the $d$ orbitals of the $A$ atom (Ca) and the $p$ orbitals of the $B$ atom (Bi or Pb). These two sets of orbitals have opposite parities, leading to two possible band orderings at $\Gamma$. The normal ordering corresponds to the $d$ orbitals of $A$ lying above the $p$ orbitals of $B$, which is expected for an ionic insulator (e.g., Ca$_3$SnO) made of $A^{2+}$, $B^{4+}$, and $O^{2-}$, hence topologically trivial. However, Ca$_3$BiN and Ca$_3$PbO were found to have an inverted band ordering in which the energies of the $d$ and $p$ orbitals are switched. Such a band inversion in antiperovskites can be induced by decreasing the lattice constant or changing the chemical elements (e.g., Sn$\rightarrow$Pb). However, because of the fourfold degeneracy of the $J = \frac{3}{2}$ multiplet, this band inversion does not change the product of parity eigenvalues of the valence bands. It then follows from the parity criterion [36] that antiperovskites with inverted gaps are not topological insulators, as correctly pointed out in Refs. [34,35].

Here we show that despite being trivial in the $Z_2$ classification of TIs, inverted antiperovskites are TCIs in the same universality class as SnTe, which are protected by mirror symmetry and indexed by an integer topological invariant known as mirror Chern number [37]. We find a nonzero mirror Chern number $[\nu_{\text{M}}] = 1 + 1 = 2$ arises from the aforementioned band inversion between $J = \frac{3}{2}$ quartets in antiperovskites. Remarkably, near the band inversion transition, the low-energy theory of antiperovskites at $\Gamma$ is described by a novel generalization of a three-dimensional Dirac fermion to eight-component and spin-3/2, which we term “Dirac octet.”

We first present first-principles calculations of the band structures of three antiperovskite compounds: Sr$_3$PbO, Sr$_3$SnO, and Ca$_3$SnO [see Figs. 1(b)–1(d)]. Our calculations were performed in the framework of density functional theory, by using the Perdew-Burke-Ernzerhof generalized gradient approximation [38] and the projector augmented-wave potential [39], as implemented in the Vienna ab initio simulation package [40]. The energy cutoff of the plane-wave basis is 400 eV. The $11 \times 11 \times 11$ Monkhorst-Pack $k$ points are used for bulk calculations. Structural relaxations are performed with forces converged to less than 0.001 eV/Å, and spin-orbit coupling is included. To overcome the underestimation of band gap, we employed Heyd-Scuseria-Ernzerhof screened Coulomb hybrid density functionals [41] to calculate the bulk electronic structures. By analyzing band parities at $\Gamma$ as mentioned above, we find that Ca$_3$SnO and Sr$_3$PbO belong to the normal and inverted regime, respectively, with opposite orderings of $d$ and $p$ orbitals, while Sr$_3$SnO lies very close to the topological phase transition point. Moreover, we find that Ca$_3$PbO, Ba$_3$PbO, Ca$_3$SiO, Ca$_3$GeO, Ca$_3$SnO, Ca$_3$BiN,
and Sr$_3$BiN are also candidate TCI s (see Supplemental Material [42]).

As a main result of this work, we now reveal the implication of the above band inversion in the context of TCI. For this purpose, we first develop $kp$ theory for this wide class of antiperovskites. We find that to linear order in $k$, the cubic point group symmetry dictates the following eight-band $kp$ Hamiltonian describing the $J=\frac{3}{2}$ conduction and valence bands near $\Gamma$:

$$H(k) = m\tau_z + v_1\tau_x k \cdot \vec{J} + v_2\tau_y k \cdot \vec{J}.$$  (1)

Here $\tau$ are Pauli matrices with $\tau_\pm = \pm 1$ labeling the valence and conduction band orbitals. $\vec{J}$ are the spin-$3/2$ matrices and $\vec{J}$ are the only other set of $4 \times 4$ matrices which transform like the vector $k$ under the cubic point group [42]. The form of the above $kp$ Hamiltonian is uniquely determined by requiring invariance under spatial inversion (represented by $P = \tau_z$), time reversal ($T = e^{-i\pi J_y} K$, $K$ being complex conjugation), and discrete rotations of the cubic group $O_h$ generated by $\vec{J}$ which act on spin and spatial coordinates simultaneously.

The Hamiltonian (1) can be regarded as a novel generalization of the Dirac Hamiltonian in three dimensions, involving an octet of spin-$3/2$ relativistic fermions that form two fourfold degenerate multiplets at $k = 0$ protected by the cubic point group symmetries. Moreover, Eq. (1) involves two velocities, leading to two sets of direction-dependent energy-momentum dispersions. In a special limit to be discussed later, Eq. (1) reduces to two identical copies of Dirac fermions.

We now analyze the mirror Chern number of $H(k)$. There are two sets of symmetry-equivalent mirror planes: (001) and (110). Let us first consider the symmetry of reflection with respect to the (100) mirror plane: $x \to -x$, which is represented by $M = PC_2 = \tau_x e^{-i\pi J_y}$, where $C_2$ is rotation by $\pi$ about the $x$ axis. Note that because $M^2 = -1$, its eigenvalues are $\pm i$. Due to this mirror symmetry, the eight-band Hamiltonian $H(k_x = 0, k_y, k_z)$ commutes with $M$ and thus decouples into two mirror subspaces, with mirror eigenvalue $\pm i$. The four states that span a given mirror subspace are given by the eigenstates of $J_x$, whose $\tau_z$ eigenvalue is locked to $J_x$ eigenvalue. The corresponding four-band Hamiltonian $H_{\pm i}(k_y, k_z)$ within a mirror subspace is given by

$$H_{\pm i}(k_y, k_z) = \mp m(ie^{-i\pi J_y}) + \sum_{i=x, y, z} k_i(v_1 J_i + v_2 \tilde{J}_i).$$  (2)

Remarkably, we find the mirror Chern number $n_M$ depends on not only the sign of $m$ which controls the band inversion at $\Gamma$, but also the velocities $v_1$ and $v_2$. We find it convenient to use the linear combinations $v_\alpha \equiv v_1/2 - v_2$, $v_\beta \equiv v_1 + v_2/2$ for velocities, and plot the topological phase diagram as a function of $m$ and $R \equiv |v_\alpha/v_\beta|$ in Fig. 2, which consists of three distinct phases with $n_M = 0, 2$, and $-2$. To obtain this result, we first consider a special limit $v_\beta = 0$, for which the four-band Hamiltonian $H_{\pm i}(k_y, k_z)$ reduces to two identical flavors of two-component Dirac Hamiltonian:

$$H_{\pm i}^{v_\beta=0}(k_y, k_z) = \mp m\Gamma_0 + v_\alpha(k_1 - k_2 \Gamma_2),$$  (3)

where the $4 \times 4$ gamma matrices are found to be $\Gamma_0 \equiv \sigma_z \otimes 1$, $\Gamma_1 \equiv \sigma_z \otimes \sigma_z$, and $\Gamma_2 \equiv \sigma_z \otimes \sigma_z$ (written here in the $j_z$ basis), which forms the $SU(2)$ algebra. When the Dirac mass $m$ changes sign, the Chern number of the $\pm i$ mirror sector changes by $\mp 2$, where the factor of 2 is due to the flavor degeneracy. Therefore, as $m$ changes from positive to negative, the mirror Chern number changes from $n_M = 0$ to $n_M = 2$. In accordance with convention, we designate $m > 0$ to the trivial

![FIG. 1. (Color online) (a) Crystal structure of the antiperovskite $A_3BX$. (b) Band structure of TCI Sr$_3$PbO in which the orbital character of valence and conduction bands within a Dirac octet is inverted ($\pm$ denotes the parities of the band orbitals). The inset depicts a fit with the $\Gamma X$ direction. (c) Sr$_3$SnO is near a topological phase transition with gap closing at $\Gamma$. (d) Ca$_3$SnO is a trivial insulator.](image)

![FIG. 2. (Color online) Topological phase diagram for the minimal quadratic $kp$ theory describing a Dirac octet, for the (100) mirror plane. The three phases have different mirror Chern numbers ($n_M$). Each inset is a schematic band structure depicting bulk states in light blue and surface states in dark blue, cutting through the bulk gap. The existence of the surface states is dictated by $n_M$.](image)
phase with normal band ordering as in Ca₃SnO, and $m < 0$ to the TCI phase with inverted band ordering as in Sr₃PbO.

To determine the mirror Chern number for $v_\alpha \neq 0$, we need to account for potential gap closings even when $m$ is fixed to be nonzero. For this, we go beyond linear order in $k$ and simply make the replacement

$$m \to m + \alpha k^2 \quad (4)$$

where $\alpha > 0$. This is similar to the quadratic term in the Bernevig-Hughes-Zhang model [43]. While several $O(k^2)$ terms are allowed by symmetry, we focus on the above for simplicity and find that quantitatively reproduces the band dispersion from \textit{ab initio} calculations [Fig. 1(b)], especially in the inverted regime.

To gain intuition for the band dispersion, first consider the limit of zero hybridization between valence and conduction orbitals ($v_\alpha = v_\delta = 0$). In the trivial regime ($m > 0$), the conduction and valence bands do not cross. However, in the inverted regime ($m < 0$), the bands cross at $\sqrt{|m|/\alpha}$ and restoring the hybridization ($v_\alpha, v_\delta$) opens a gap at this crossing.

Importantly, we find that tuning the ratio $v_\delta/v_\alpha$ closes and reopens this gap along the $\Gamma X$ directions, with criticality at $v_\alpha/v_\delta = \pm 1$. To model this gap behavior, we derive the most general $kp$ theory for this avoided crossing in the Supplemental Material and we state the result here:

$$H_k = m_0 \sigma_z + v_\delta \delta k_\parallel (y + s_\alpha \sigma_x) + v(k_x s_y - k_y s_x) \sigma_x.$$

Here $s_\alpha = \pm 1$ denotes the Kramers pair ($j_\alpha = \pm 3/2$), $\sigma_z = \pm 1$ denote valence and conduction band orbitals, $m_0$ is the mass term determining the gap, and $v$ and $v_\delta, v_\gamma$ govern the velocities of dispersion in the $x(y), z$ directions. $\delta k_\parallel \equiv k_z - k_0$, where $k_0$ is the momentum at which the gap is minimum, if $\gamma = 0$. Since there are four such $\Gamma X$ directions on the $k_z = 0$ mirror plane, every time the four gaps close and reopen (corresponding to $m_0$ changing sign), the mirror Chern number (of the $k_z = 0$ mirror plane) changes by $4$.

Therefore, in going from the previously analyzed limit $|v_\delta/v_\alpha| = \infty \to |v_\delta/v_\alpha| = 0$, the mirror Chern number changes from $n_M = 2$ to $n_M = -2$ at $|v_\delta/v_\alpha| = 1$. In the Supplemental Material, we provide a detailed derivation of this. The phase diagram is shown in Fig. 2; we emphasize that in the inverted regime, the phases are always topologically nontrivial $|n_M| = 2$. Unlike the SnTe class of materials, in which band inversion of spin-1/2 fermions at different points in momentum space add up to yield $|n_M| = 2$, here the band inversion occurs at a single point $\Gamma$ and it is the spin-3/2 nature of the octet which yields $|n_M| = 2$.

Our theory thus captures and deduces the consequences of two essential features of the band structure of several antiperovskites: (1) the band inversion of the octet at $\Gamma$ which as shown above gives rise to (2) a small gap (avoided crossing) at finite momentum along $\Gamma X$ in such band inverted antiperovskites. Previous works by Kariyado and Ogata [35,44] have focused on this finite $k$ avoided crossing at the Fermi energy; they attributed the smallness of the gap (15 meV for Ca₃PbO) to the combination of hybridization with orbital states away from the Fermi energy and spin-orbit coupling. While prior works have emphasized the massive Dirac fermions at finite $k$ near $\Gamma$, the main feature of this work is the “parent” Dirac

![FIG. 3. (Color online) Topological phase diagram for the minimal quadratic $kp$ theory of the (110) mirror plane. The numbers $n_M$ are the mirror Chern numbers.](image-url)
The experimental feasibility of thin film and heterostructure growth, strain, and alloying may add to the already diverse features of this material class. As thin films of SnTe are examples of two-dimensional topological crystalline insulators protected by mirror symmetry about the film plane [12], it is possible that thin films of antiperovskites may also be topologically nontrivial. One may expect that both the inverted octet at \( \Gamma \) and the small avoided crossing at finite \( k \) can be tunable with layer thickness. Moreover, given the wealth of phenomena in perovskite heterostructures and interfaces [45–48], it is likely that similarly diverse features can be found in the antiperovskite counterparts. Likewise, applying strain serves as yet another experimental knob on these two gaps which will affect the topological class of the material [34]. Finally, by applying pressure or tuning the chemical composition to interpolate between a trivial and topological phase transition.

We conclude that the antiperovskite family hosts a rich variety of features, now encompassing topology and symmetry. The existence of the Dirac octet at \( \Gamma \) undergoing band inversion leads to their classification as topological crystalline insulators endowed with robust metallic surface states. The presence of the high spin fermions fits naturally with the notion of TCIs, which allow for an even number of band inversions unlike \( Z_2 \) topological insulators. The Dirac octet fermions are quite distinct from typical four-component Dirac or two-component Weyl fermions, and the topological phase diagram for the full \( kp \) theory to quadratic order is expected to be quite rich. These new ingredients of topology, symmetry, and the high spin Dirac octet make the antiperovskite family a promising playground for experimental and theoretical developments.

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[42] See Supplemental Material at http://link.aps.org/supplemental/10.1103/PhysRevB.90.081112 for a detailed derivation of phase diagrams in Figs. 2 and 3, explicit form of the matrices in the kp model, kp model for the finite k crossing, and band structure calculations of other antiperovskites which are potentially TCIs.


